NSN 5961-01-544-6976

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Internal Configuration
Internal Configuration:
Field effect
Mounting Method:
Terminal
Features Provided:
Electrostatic sensitive
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1000.0 drain to source voltage
Current Rating Per Characteristic:
5.00 amperes all primaries of standard range
Terminal Type And Quantity:
3 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

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